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**TEXAS
INSTRUMENTS**

CSD18532NQ5B

SLPS440A –JUNE 2013–REVISED DECEMBER 2015

CSD18532NQ5B 60 V N-Channel NexFET™ Power MOSFET

1 Features

- Ultra-Low Q_g and Q_{gd}
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5 mm × 6 mm Plastic Package

2 Applications

- DC-DC Conversion
- Secondary Side Synchronous Rectifier
- Isolated Converter Primary Side Switch
- Motor Control

3 Description

This 60 V, 2.7 mΩ, 5 × 6 mm SON NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.

Product Summary

$T_A = 25^\circ\text{C}$		TYPICAL VALUE		UNIT
V_{DS}	Drain-to-Source Voltage	60		V
Q_g	Gate Charge Total (10 V)	49		nC
Q_{gd}	Gate Charge Gate to Drain	7.9		nC
$R_{DS(on)}$	Drain-to-Source On-Resistance	$V_{GS} = 6\text{ V}$	3.5	mΩ
		$V_{GS} = 10\text{ V}$	2.7	mΩ
$V_{GS(th)}$	Threshold Voltage	2.8		V

Ordering Information

DEVICE	QTY	MEDIA	PACKAGE	SHIP
CSD18532NQ5B	2500	13-Inch Reel	SON 5 mm × 6 mm Plastic Package	Tape and Reel
CSD18532NQ5BT	250	7-Inch Reel		

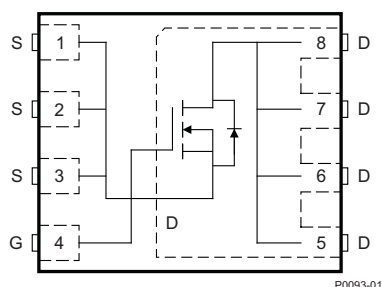
Absolute Maximum Ratings

$T_A = 25^\circ\text{C}$		VALUE	UNIT
V_{DS}	Drain to Source Voltage	60	V
V_{GS}	Gate to Source Voltage	±20	V
I_D	Continuous Drain Current (Package limited)	100	A
	Continuous Drain Current (Silicon limited), $T_C = 25^\circ\text{C}$	151	
	Continuous Drain Current ⁽¹⁾	21	
I_{DM}	Pulsed Drain Current ⁽²⁾	400	A
P_D	Power Dissipation ⁽¹⁾	3.1	W
	Power Dissipation, $T_C = 25^\circ\text{C}$	156	
T_J , T_{stg}	Operating Junction Temperature, Storage Temperature	–55 to 150	°C
E_{AS}	Avalanche Energy, single pulse $I_D = 85\text{ A}$, $L = 0.1\text{ mH}$, $R_G = 25\text{ }\Omega$	360	mJ

(1) Typical $R_{\theta JA} = 40^\circ\text{C/W}$ on a 1 inch², 2 oz. Cu pad on a 0.06 inch thick FR4 PCB.

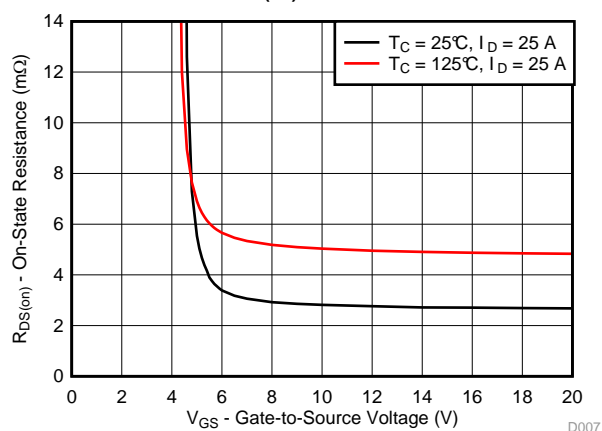
(2) Max $R_{\theta JC} = 0.8^\circ\text{C/W}$, Pulse duration ≤100 μs, duty cycle ≤1%.

Top View



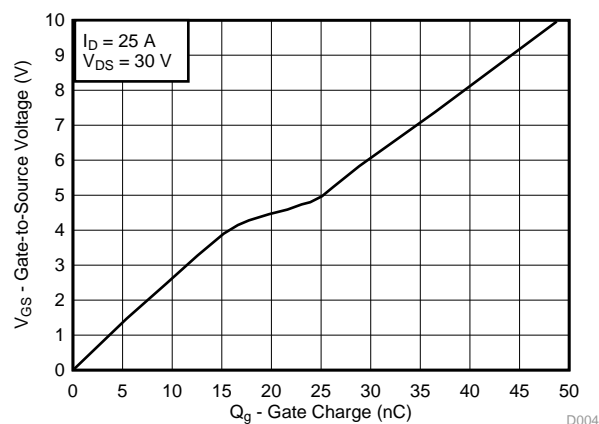
P0093-01

$R_{DS(on)}$ vs V_{GS}



D007

Gate Charge



D004



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CSD18532NQ5B

SLPS440A –JUNE 2013–REVISED DECEMBER 2015

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Table of Contents

1 Features	1	6.1 Community Resources	7
2 Applications	1	6.2 Trademarks	7
3 Description	1	6.3 Electrostatic Discharge Caution	7
4 Revision History	2	6.4 Glossary	7
5 Specifications	3	7 Mechanical, Packaging, and Orderable Information	8
5.1 Electrical Characteristics	3	7.1 Q5B Package Dimensions	8
5.2 Thermal Information	3	7.2 Recommended PCB Pattern	9
5.3 Typical MOSFET Characteristics	4	7.3 Recommended Stencil Pattern	9
6 Device and Documentation Support	7	7.4 Q5B Tape and Reel Information	10

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (June 2014) to Revision A	Page
• Added part number to title	1
• Added 7" reel to <i>Ordering Information</i>	1
• Updated pulsed current conditions	1
• Added line for Power Dissipation, $T_C = 25^\circ\text{C}$ in <i>Absolute Maximum Ratings</i> table	1
• Updated Figure 1 to show $R_{\theta JC}$ curves	4
• Updated SOA in Figure 10	6
• Added <i>Device and Documentation Support</i> section	7
• Updated <i>Mechanical, Packaging, and Orderable Information</i> and mechanical drawings	8

5 Specifications

5.1 Electrical Characteristics

($T_A = 25^\circ\text{C}$ unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC CHARACTERISTICS						
BV _{DSS}	Drain-to-source voltage	V _{GS} = 0 V, I _D = 250 μA	60			V
I _{DSS}	Drain-to-source leakage current	V _{GS} = 0 V, V _{DS} = 48 V			1	μA
I _{GSS}	Gate-to-source leakage current	V _{DS} = 0 V, V _{GS} = 20 V			100	nA
V _{GS(th)}	Gate-to-source threshold voltage	V _{DS} = V _{GS} , I _D = 250 μA	2.4	2.8	3.4	V
R _{DS(on)}	Drain-to-source on-resistance	V _{GS} = 6 V, I _D = 25 A		3.5	4.4	mΩ
		V _{GS} = 10 V, I _D = 25 A		2.7	3.4	mΩ
g _{fs}	Transconductance	V _{DS} = 30 V, I _D = 25 A		140		S
DYNAMIC CHARACTERISTICS						
C _{iss}	Input capacitance	V _{GS} = 0 V, V _{DS} = 30 V, f = 1 MHz		4100	5340	pF
C _{oss}	Output capacitance			495	644	pF
C _{rss}	Reverse transfer capacitance			16	21	pF
R _G	Series gate resistance			1.2	2.4	Ω
Q _g	Gate charge total (10 V)	V _{DS} = 30 V, I _D = 25 A		49	64	nC
Q _{gd}	Gate charge gate to drain			7.9		nC
Q _{gs}	Gate charge gate to source			16		nC
Q _{g(th)}	Gate charge at V _{th}			11		nC
Q _{oss}	Output charge	V _{DS} = 30 V, V _{GS} = 0 V		69		nC
t _{d(on)}	Turn on delay time	V _{DS} = 30 V, V _{GS} = 10 V, I _{DS} = 25 A, R _G = 0 Ω		8.2		ns
t _r	Rise time			8.7		ns
t _{d(off)}	Turn off delay time			20		ns
t _f	Fall time			2.7		ns
DIODE CHARACTERISTICS						
V _{SD}	Diode forward voltage	I _{SD} = 25 A, V _{GS} = 0 V		0.8	1	V
Q _{rr}	Reverse recovery charge	V _{DS} = 30 V, I _F = 25 A, di/dt = 300 A/μs		139		nC
t _{rr}	Reverse recovery time			64		ns

5.2 Thermal Information

($T_A = 25^\circ\text{C}$ unless otherwise stated)

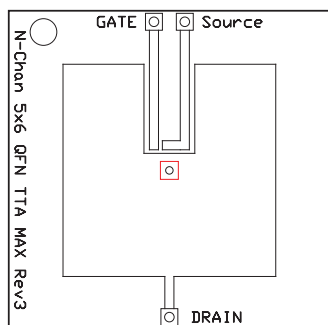
THERMAL METRIC		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-case thermal resistance ⁽¹⁾			0.8	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽¹⁾⁽²⁾			50	$^\circ\text{C}/\text{W}$

- $R_{\theta JC}$ is determined with the device mounted on a 1 inch² (6.45 cm²), 2 oz. (0.071 mm thick) Cu pad on a 1.5 inch × 1.5 inch (3.81 cm × 3.81 cm), 0.06 inch (1.52 mm) thick FR4 PCB. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design.
- Device mounted on FR4 material with 1 inch² (6.45 cm²), 2 oz. (0.071 mm thick) Cu.

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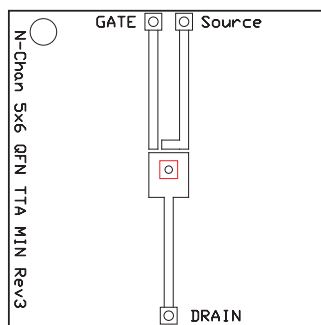
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Max $R_{\theta JA} = 50^{\circ}\text{C/W}$
when mounted on
1 inch² (6.45 cm²) of 2
oz. (0.071 mm thick)
Cu.

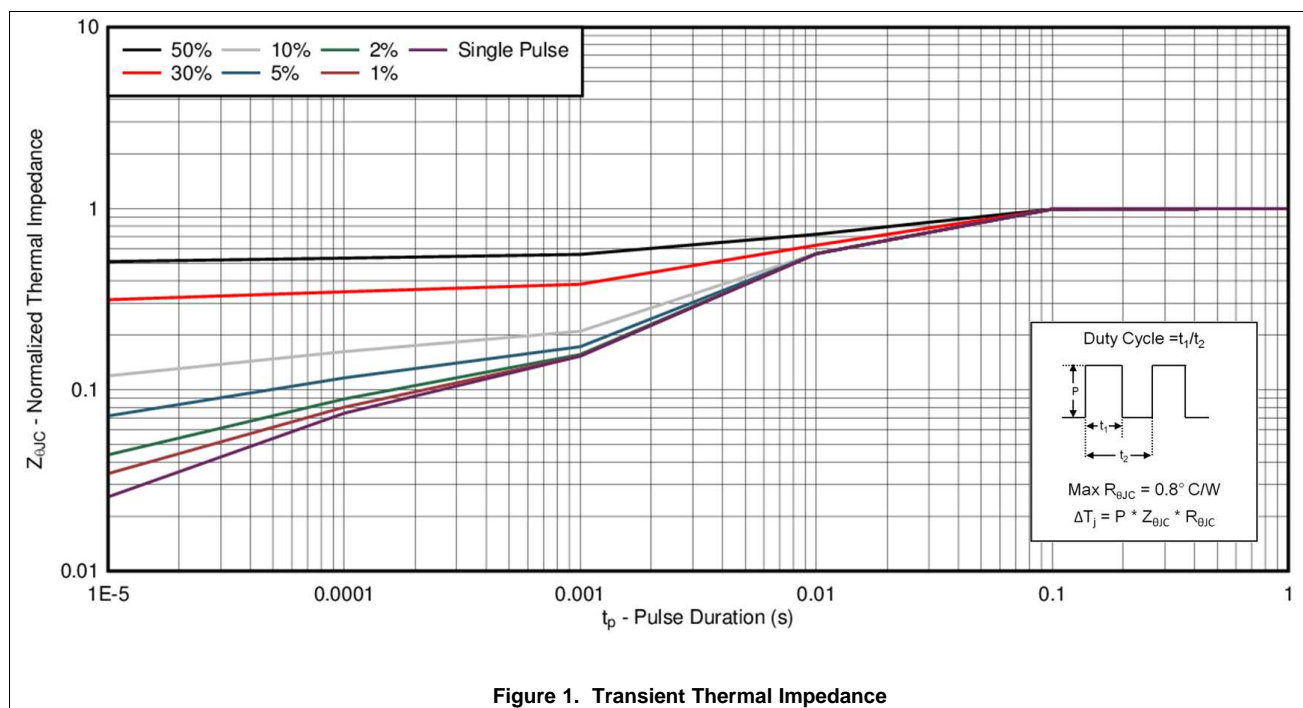


M0137-02

Max $R_{\theta JA} = 125^{\circ}\text{C/W}$
when mounted on a
minimum pad area of 2
oz. (0.071 mm thick)
Cu.

5.3 Typical MOSFET Characteristics

($T_A = 25^{\circ}\text{C}$ unless otherwise stated)



Typical MOSFET Characteristics (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

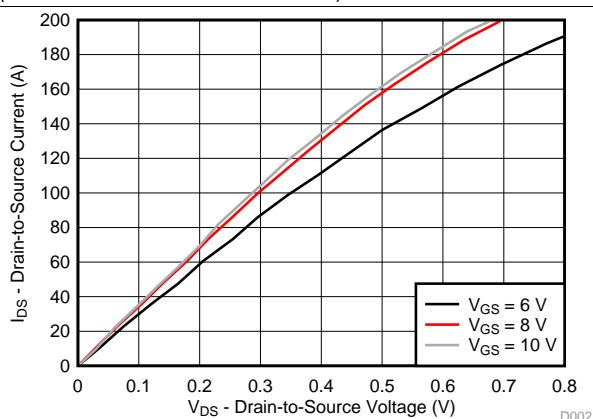


Figure 2. Saturation Characteristics

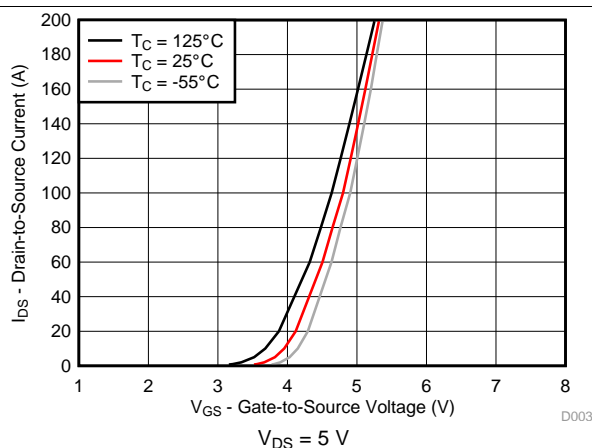


Figure 3. Transfer Characteristics

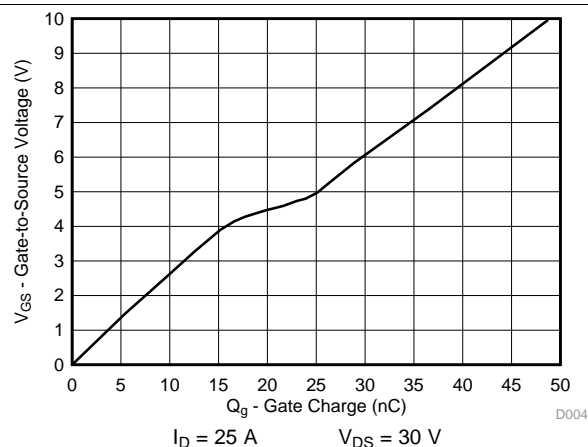


Figure 4. Gate Charge

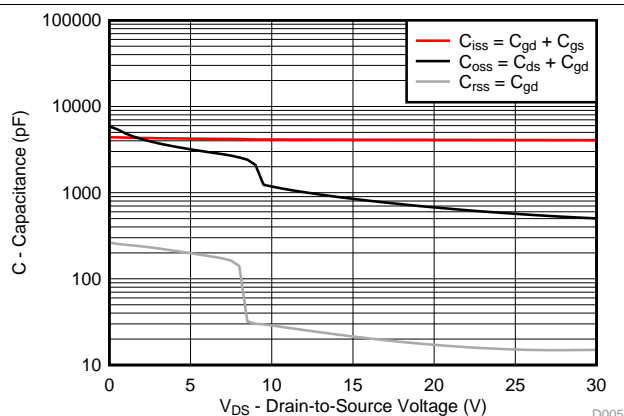


Figure 5. Capacitance

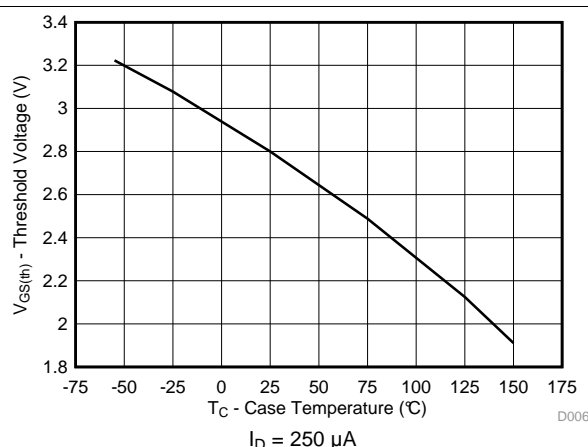


Figure 6. Threshold Voltage vs Temperature

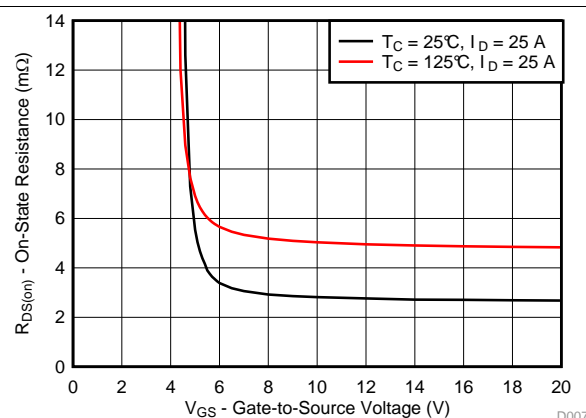


Figure 7. On-State Resistance vs Gate-to-Source Voltage

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Typical MOSFET Characteristics (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

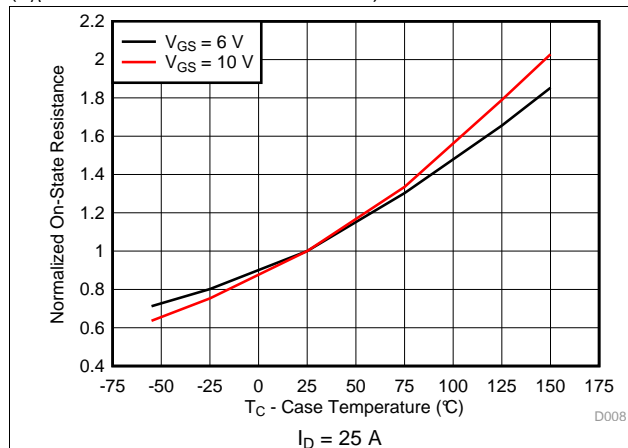


Figure 8. Normalized On-State Resistance vs Temperature

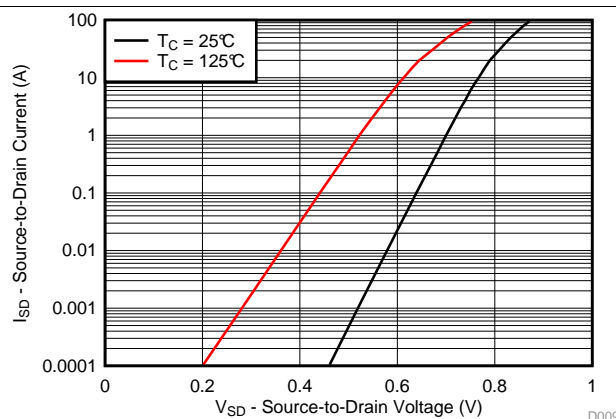


Figure 9. Typical Diode Forward Voltage

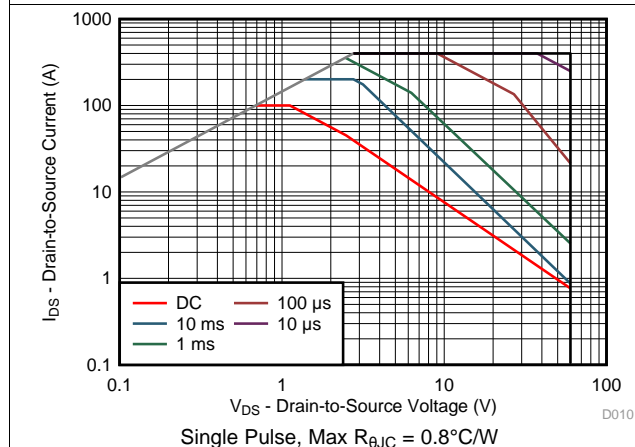


Figure 10. Maximum Safe Operating Area

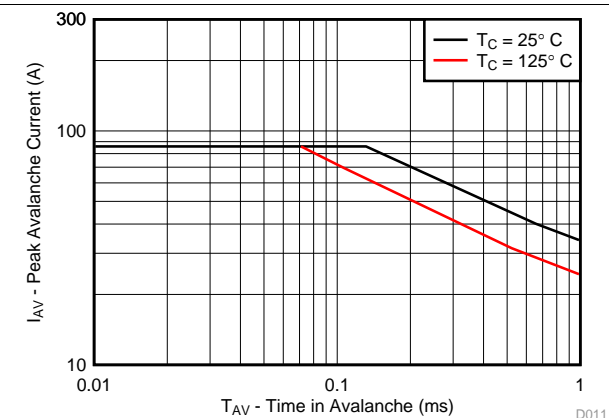


Figure 11. Single Pulse Unclamped Inductive Switching

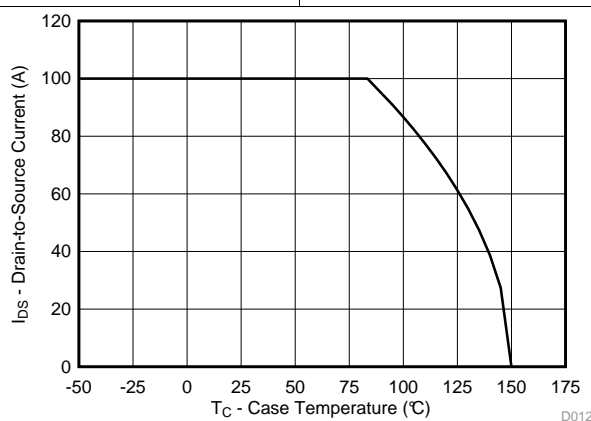


Figure 12. Maximum Drain Current vs Temperature

6 Device and Documentation Support

6.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

6.2 Trademarks

NexFET, E2E are trademarks of Texas Instruments.

All other trademarks are the property of their respective owners.

6.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.4 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

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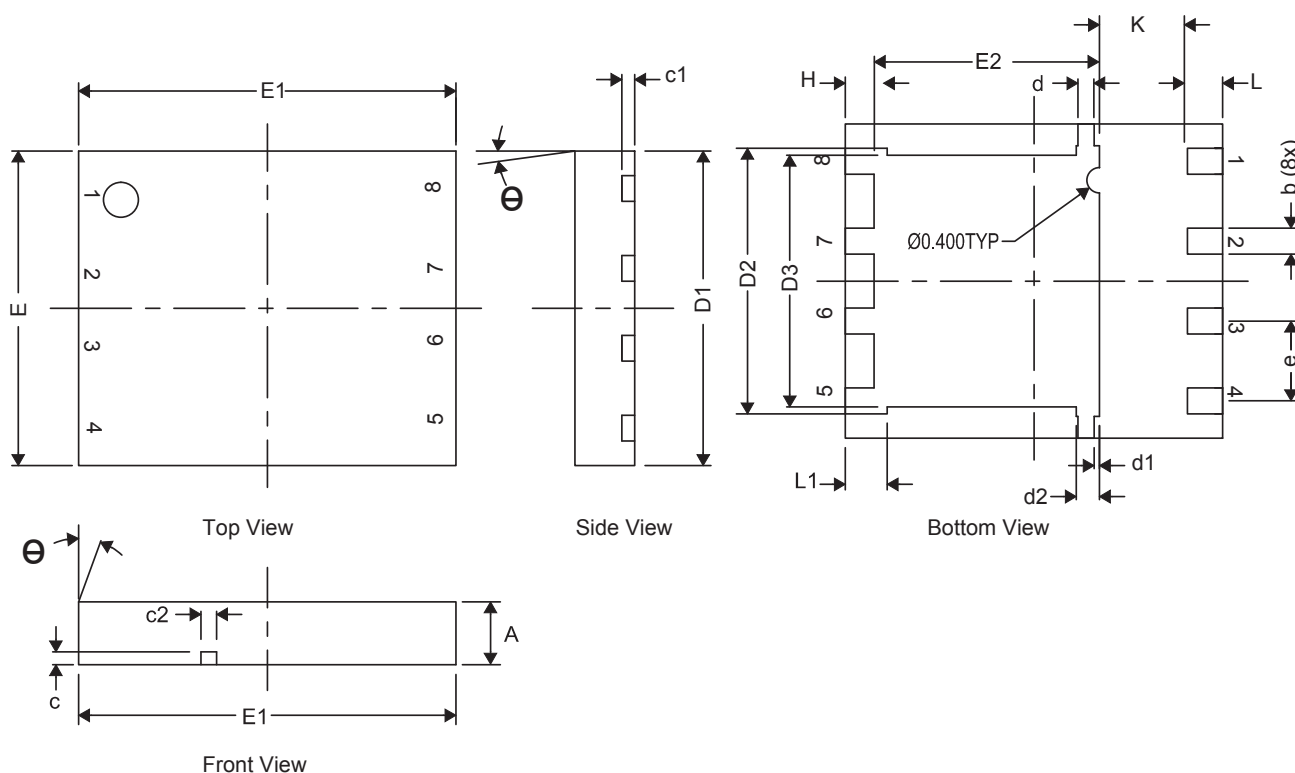
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7 Mechanical, Packaging, and Orderable Information

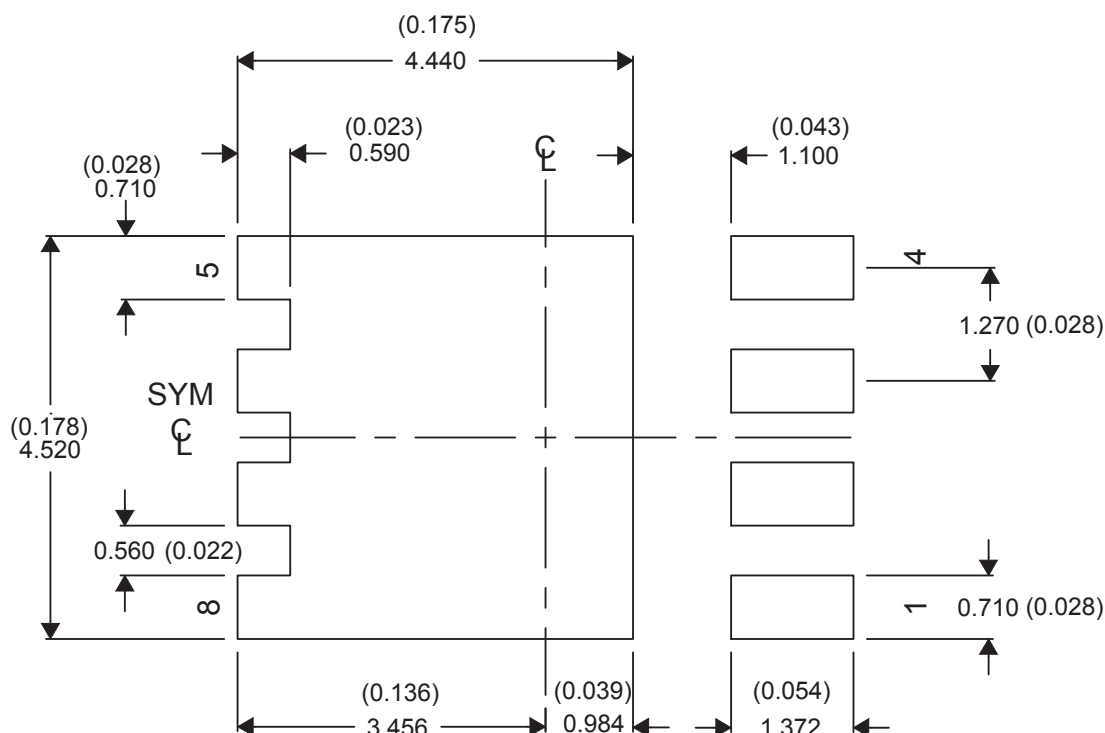
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 Q5B Package Dimensions



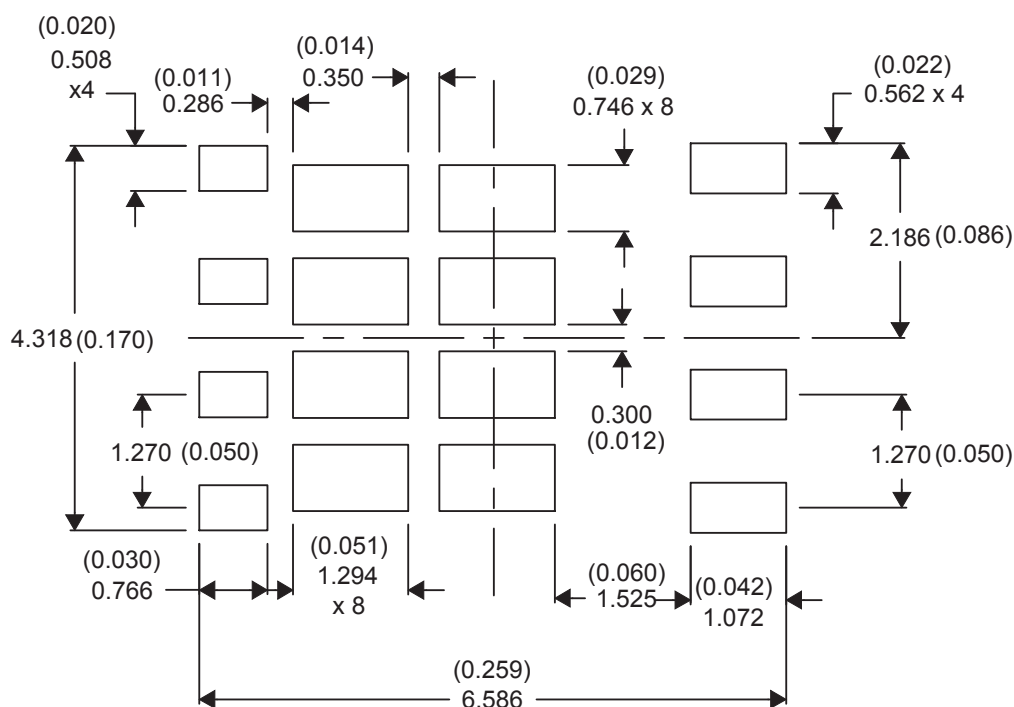
DIM	MILLIMETERS		
	MIN	NOM	MAX
A	0.80	1.00	1.05
b	0.36	0.41	0.46
c	0.15	0.20	0.25
c1	0.15	0.20	0.25
c2	0.20	0.25	0.30
D1	4.90	5.00	5.10
D2	4.12	4.22	4.32
d	0.20	0.25	0.30
E	4.90	5.00	5.10
E1	5.90	6.00	6.10
E2	3.48	3.58	3.68
e	1.27 TYP		
L	0.46	0.56	0.66
theta	0°	—	—
K	1.40 TYP		

7.2 Recommended PCB Pattern



For recommended circuit layout for PCB designs, see application note [SLPA005](#) – *Reducing Ringing Through PCB Layout Techniques*.

7.3 Recommended Stencil Pattern

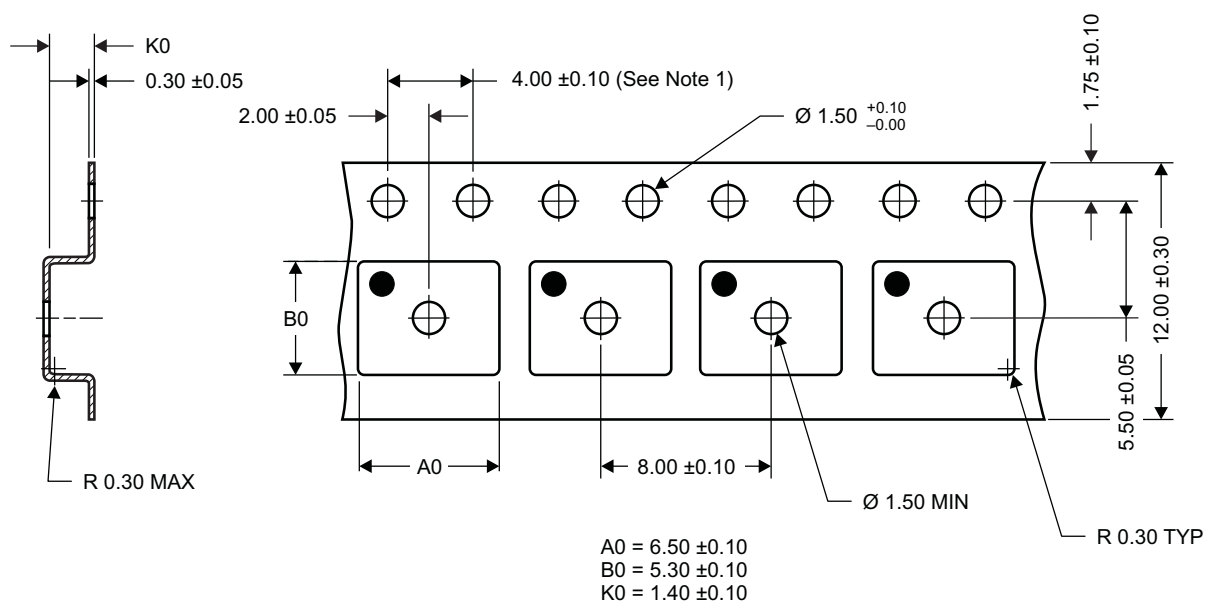


CSD18532NQ5B

SLPS440A – JUNE 2013 – REVISED DECEMBER 2015

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7.4 Q5B Tape and Reel Information



M0138-01

Notes:

1. 10-sprocket hole-pitch cumulative tolerance ± 0.2
2. Camber not to exceed 1 mm in 100 mm, noncumulative over 250 mm
3. Material: black static-dissipative polystyrene
4. All dimensions are in mm (unless otherwise specified)
5. A0 and B0 measured on a plane 0.3 mm above the bottom of the pocket



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PACKAGE OPTION ADDENDUM

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16-Mar-2016

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD18532NQ5B	ACTIVE	VSON-CLIP	DNK	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	18532N	Samples
CSD18532NQ5BT	ACTIVE	VSON-CLIP	DNK	8	250	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	18532N	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD18532NQ5B	VSON-CLIP	DNK	8	2500	330.0	12.8	6.5	5.3	1.4	8.0	12.0	Q1
CSD18532NQ5BT	VSON-CLIP	DNK	8	250	330.0	12.8	6.5	5.3	1.4	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD18532NQ5B	VSON-CLIP	DNK	8	2500	335.0	335.0	32.0
CSD18532NQ5BT	VSON-CLIP	DNK	8	250	335.0	335.0	32.0

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TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

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